Diode Semiconductor Korea

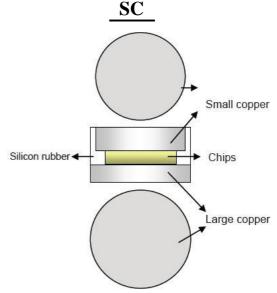
SC25A THRU SC25M 25A, 50V TO 1200V a SOZA CELL

FEATURES

High current capability .Low forward voltage drop Low leakage current High surge current capability

MECHANICAL DATA

Large copper: $\psi(5.5) \times (0.75)$ Thick



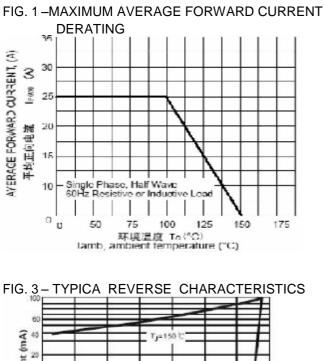
Dimension in inches(millimeters)

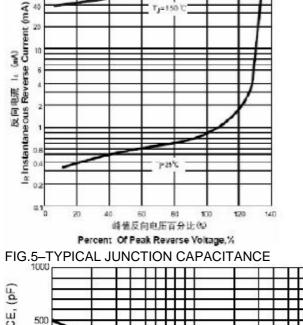
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

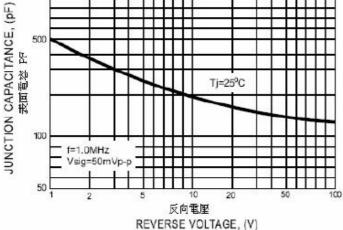
Rating at 25°C Ambient temp. Unless otherwise specified.Single phase, half sine wave, 60HZ,resistive or inductive load. For capacitive load, derate current by 20%

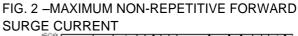
	SYMBO	o sc							
	L	25A	25B	25D	25G	25J	25K	25M	UNITS
Maximum Current Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
T∟=100℃ Maximum Average Forward Rectified Current	I(AV)	25							Amps
Peak Forward Surge Current 8.3ms Single Sine-wave on Rated Load (JEDEC Method)	IFSM	300							Amps
Maximum Instantaneous Forward Voltage Drop at 25A DC	VF	1.0							Volts
Maximum DC Reverse Current T _A =25℃ at Rated DC Blocking Voltage T _A =125℃	IR	5 250							uA
Typical Junction Capacitance (NOTE 1)	CJ	300							pF
Operating AND Storage Temperature Range	TSTG/ TJ	-55 to +150							°C

NOTE: 1.Measured at 1 MHz and Applied Reverse Voltage of 4.0 Volts D.C.









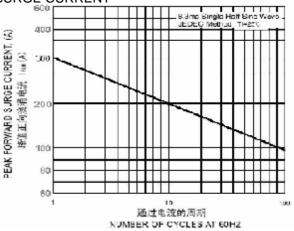


FIG.4 – TYPICA FORWARD CHARACTERISTICS

